LM195QML Ultra Reliable Power Transistors

FEATURES

- **Internal Thermal Limiting**
- **Greater Than 1.0A Output Current**
- **3.0 µA Typical Base Current**
- **500 ns Switching Time**
- **2.0V Saturation**
- **Base Can be Driven up to 40V Without Damage**
- **Directly Interfaces with CMOS or TTL**
- **100% Electrical Burn-in**

DESCRIPTION

The LM195 is a fast, monolithic power integrated circuit with complete overload protection. This device, which acts as a high gain power transistor, has included on the chip, current limiting, power limiting, and thermal overload protection making it virtually impossible to destroy from any type of overload.

The inclusion of thermal limiting, a feature not easily available in discrete designs, provides virtually absolute protection against overload. Excessive power dissipation or inadequate heat sinking causes the thermal limiting circuitry to turn off the device preventing excessive heating.

The LM195 offers a significant increase in reliability as well as simplifying power circuitry. In some applications, where protection is unusually difficult, such as switching regulators, lamp or solenoid drivers where normal power dissipation is low, the LM195 is especially advantageous.

The LM195 is easy to use and only a few precautions need be observed. Excessive collector to emitter voltage can destroy the LM195 as with any power transistor. When the device is used as an emitter follower with low source impedance, it is necessary to insert a 5.0k resistor in series with the base lead to prevent possible emitter follower oscillations. Although the device is usually stable as an emitter follower, the resistor eliminates the possibility of trouble without degrading performance. Finally, since it has good high frequency response, supply bypassing is recommended.

Connection Diagram
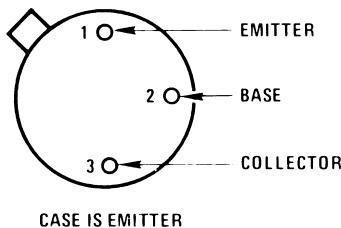
**Figure 1. 5-Pin TO - Bottom View**
**See NDT0003A Package**

Schematic Diagram
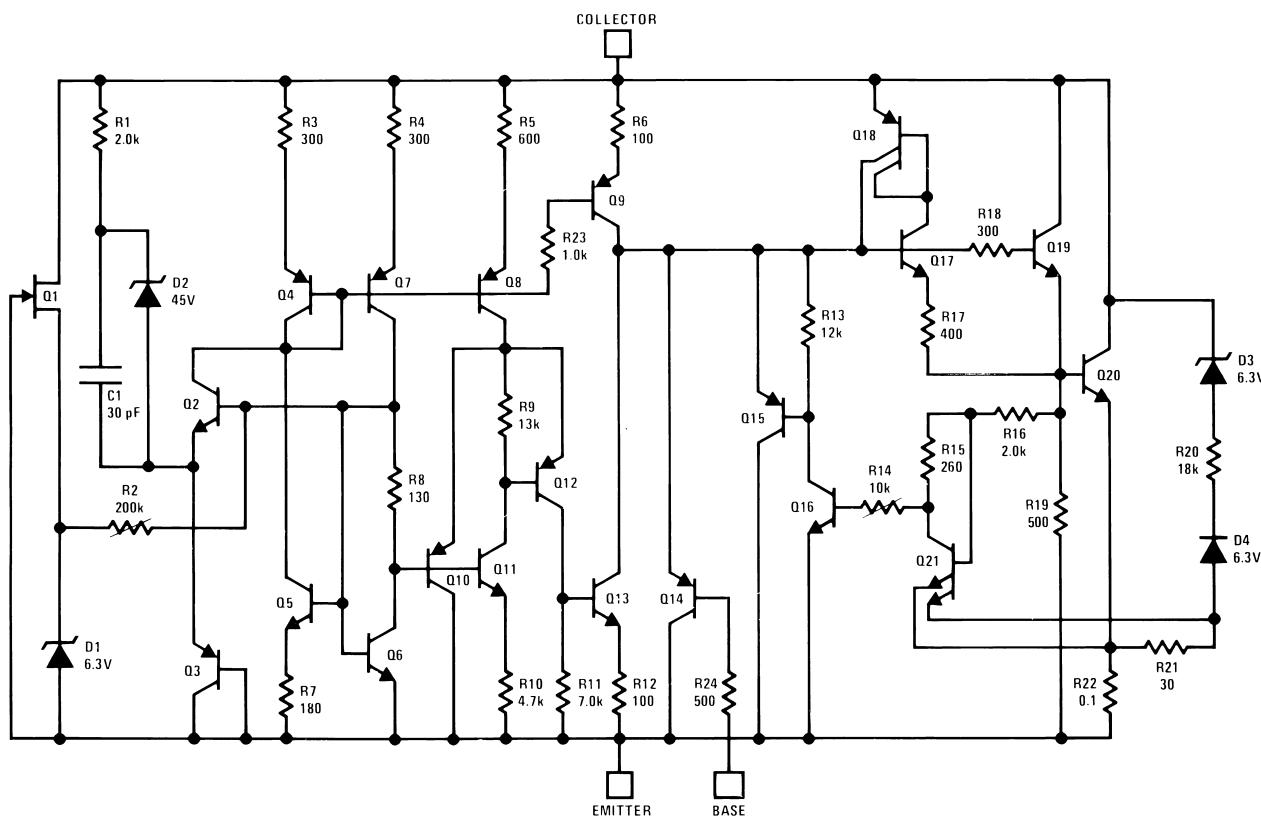
Simplified Circuit
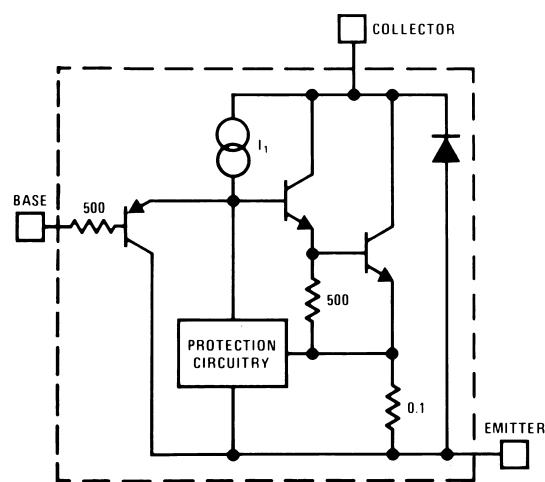
1.0 Amp Lamp Flasher
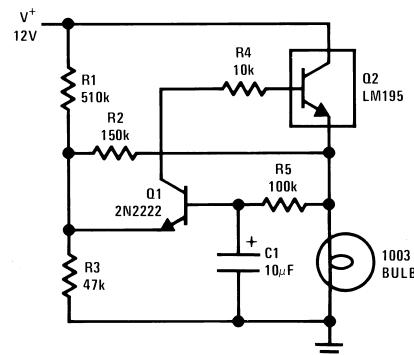
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Product Folder Links: *LM195QML LM195QML-SP*

Absolute Maximum Ratings[1]

Collector to Emitter Voltage			42V
Collector to Base Voltage			42V
Base to Emitter Voltage (Forward)			42V
Base to Emitter Voltage (Reverse)			20V
Collector Current			Internally Limited
Power Dissipation[2]			Internally Limited
Operating Temperature Range	TO package		$-55°C ≤ T_A ≤ +125°C$
Storage Temperature Range			$-65°C ≤ T_A ≤ +150°C$
Lead Temperature (Soldering, 10 sec.)			260°C
Thermal Resistance	$θ_{JA}$	TO package; Still Air at 0.5W	192°C/W
		TO package; 500LF/Min Air Flow at 0.5W	66°C/W
	$θ_{JC}$	TO package at 1.0W	29°C/W

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

(2) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{Jmax} (maximum junction temperature), $θ_{JA}$ (package junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is $P_{Dmax} = (T_{Jmax} - T_A)/θ_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower.

Quality Conformance Inspection

Table 1. Mil-Std-883, Method 5005 - Group A

Subgroup	Description	Temp (°C)
1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55
12	Settling time at	+25
13	Settling time at	+125
14	Settling time at	-55

LM195H/883 Electrical Characteristics DC Parameter Collector to Emitter

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-groups
V_{CE}	Operating Voltage	$I_C ≤ I_{Max}$	See[1]		42	V	1, 2, 3

(1) Parameter tested go−no−go only.

LM195H/883 Electrical Characteristics DC Parameter Base to Emitter

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-groups
BV_{BE}	Breakdown Voltage	$V_{CE} \leq 42V$	See[1]	42		V	1, 2, 3
I_{SC}	Collector Current	$V_{CE} \leq 7V$		1.2		A	1
				1		A	2, 3
V_{Sat}	Saturation Voltage	$I_C = 1A$			2	V	1, 2
					2.5	V	3
I_B	Base Current	$0 \leq V_{BE} \leq 42V$, $I_C \leq I_{Max}$			5	µA	1, 2, 3
I_Q	Quiescent Current	$V_{CE} = 42V$, $V_{BE} = 0V$			5	mA	1, 2, 3
V_{Bk}	Breakdown Delta V_{BE}	$V_C = 46\text{-}42V$, $I_L = 50mA$		-0.03	0.01	V	1
		$V_C = 46\text{-}38V$		-0.03	0.01	V	1
		$V_C = 50\text{-}42V$		-0.03	0.01	V	1
Thr	Thermal Response	100µS		-10	100	mV	1
		500µS		-10	70	mV	1
		2mS		-10	50	mV	1
		20mS		-10	10	mV	1

(1) Parameter tested go−no−go only.

LM195H/883 Electrical Characteristics AC Parameter

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-groups
t_{ON}	Response Time	$V_I = 0\text{-}2V$, $R_L = 36\Omega$, $V+ = 36V$			1.8	µS	9, 10, 11
t_{OFF}	Response Time	$V_I = 2\text{-}0V$, $R_L = 36\Omega$, $V+ = 36V$			1.8	µS	9, 10, 11
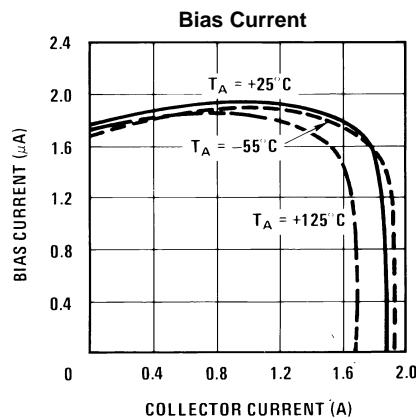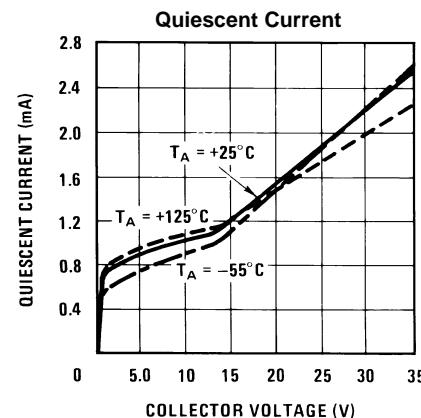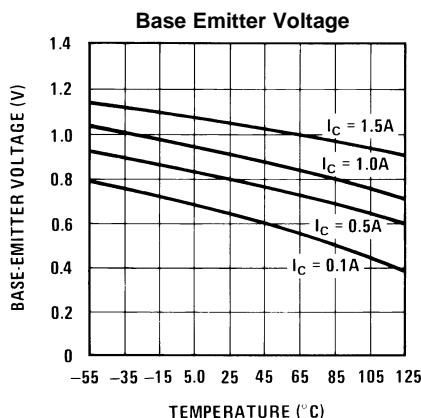
Product Folder Links: *LM195QML LM195QML-SP*

Typical Performance Characteristics

Bias Current

Figure 2.

Quiescent Current

Figure 3.

Base Emitter Voltage

Figure 4.

Base Current

Figure 5.

Saturation Voltage

Figure 6.

Response Time

Figure 7.

Typical Performance Characteristics (continued)

Response Time

Figure 8.

10V Transfer Function

Figure 9.

36V Transfer Function

Figure 10.

Transconductance

Figure 11.

Small Signal Frequency Response

Figure 12.

Product Folder Links: *LM195QML LM195QML-SP*
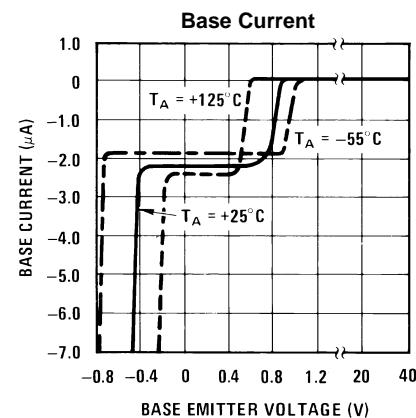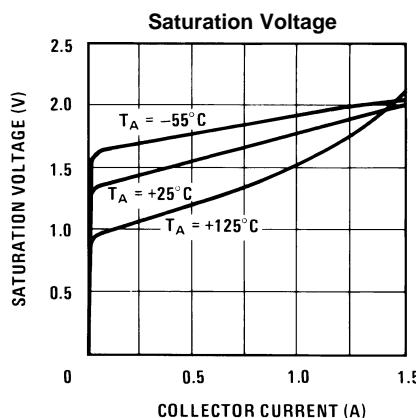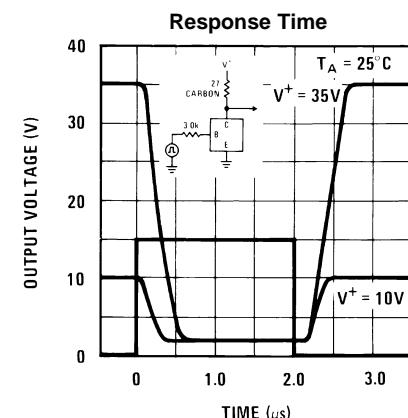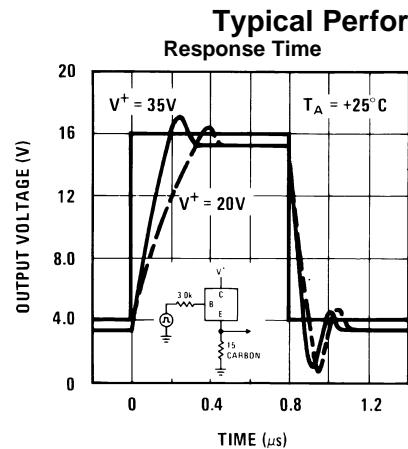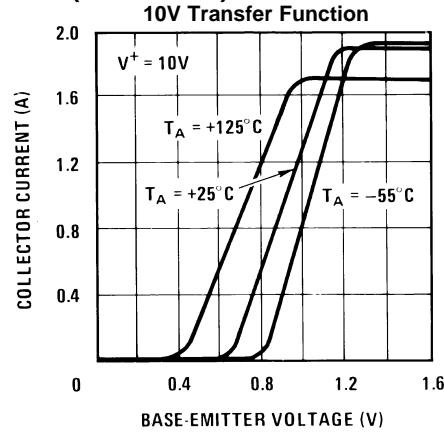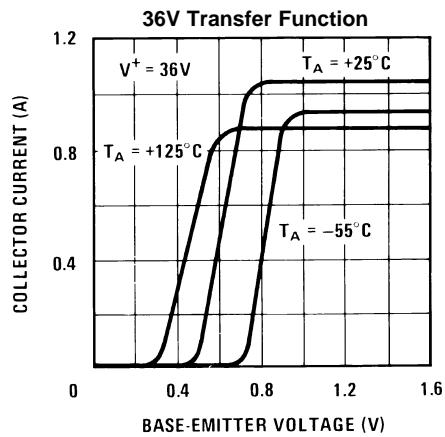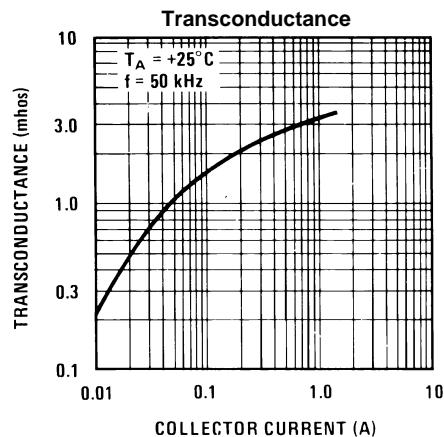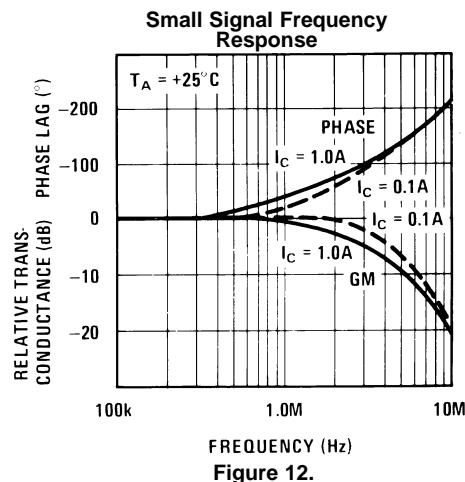
Typical Applications

1.0 Amp Voltage Follower
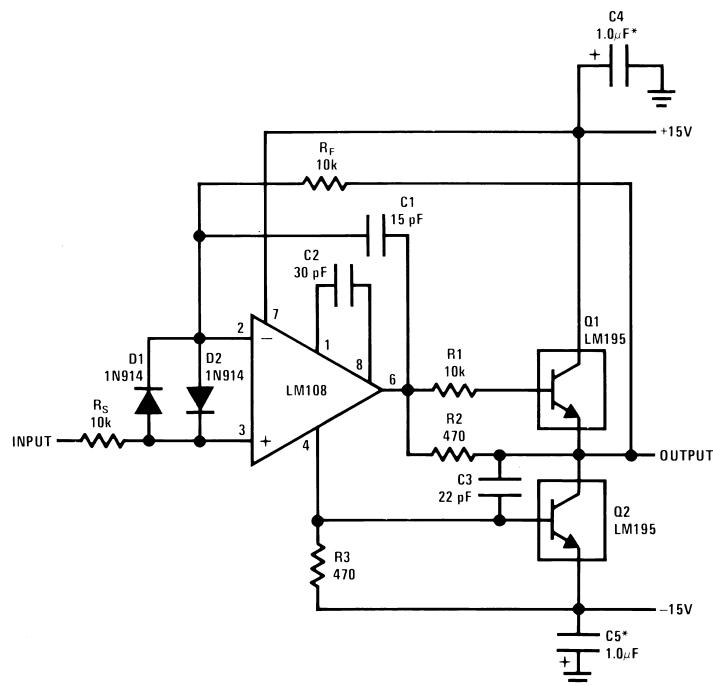
*Solid Tantalum

Power PNP
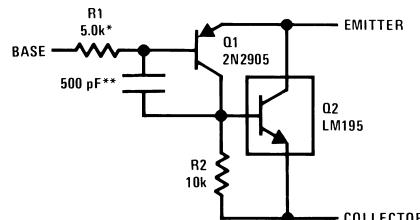
*Protects against excessive base drive
**Needed for stability

Time Delay
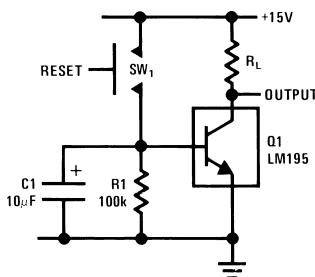
## 1.0 MHz Oscillator
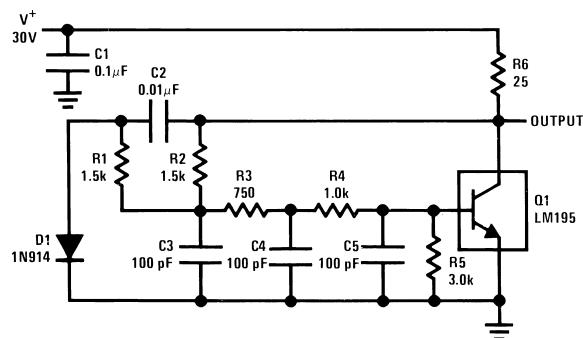
1.0 Amp Negative Regulator
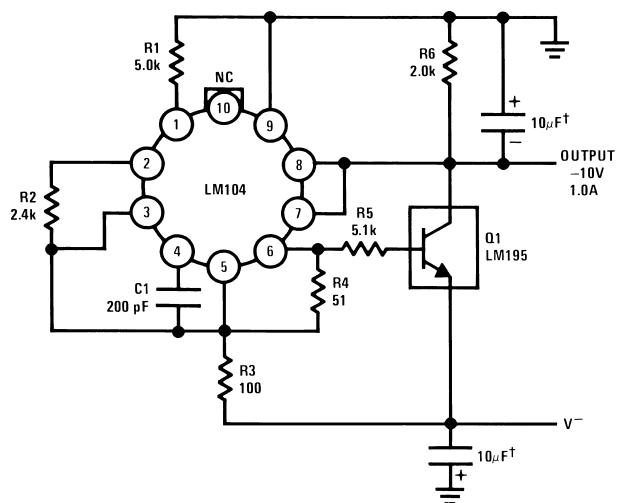
†Solid Tantalum

1.0 Amp Positive Voltage Regulator

†Solid Tantalum

Product Folder Links: *LM195QML LM195QML-SP*
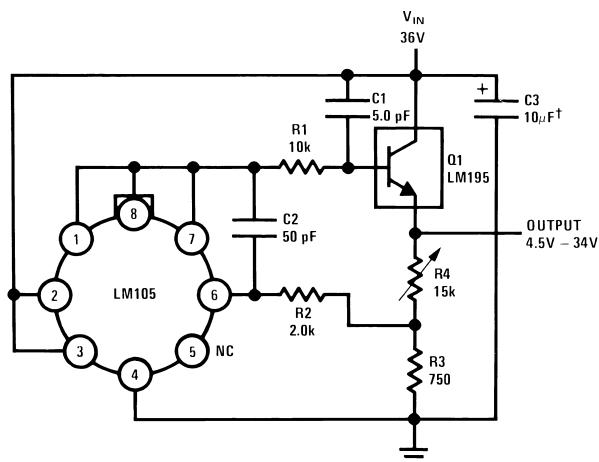
**Fast Optically Isolated Switch**
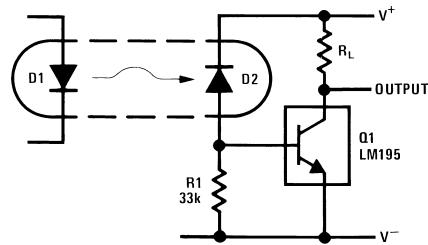
Optically Isolated Power Transistor
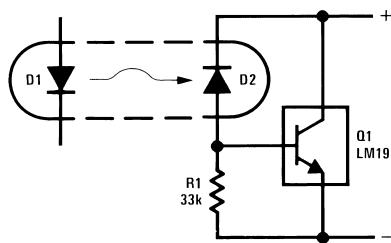
**CMOS or TTL Lamp Interface**
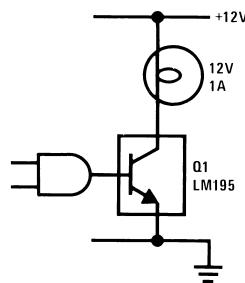
Two Terminal Current Limiter
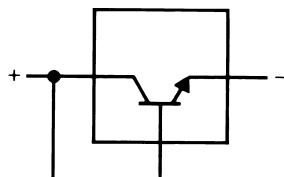
40V Switch
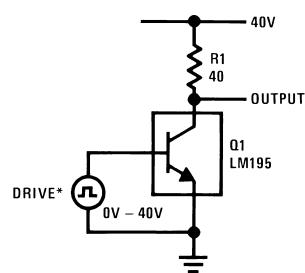
*Drive Voltage 0V to ≥ 10V ≤ 42V

6.0V Shunt Regulator with Crowbar
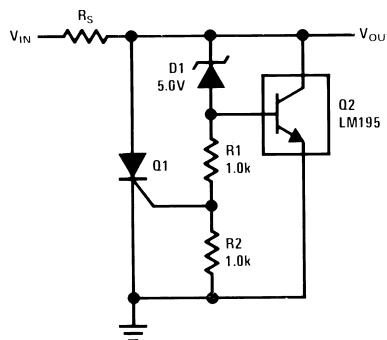
Two Terminal 100 mA Current Regulator
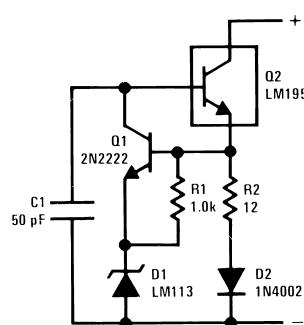
Low Level Power Switch
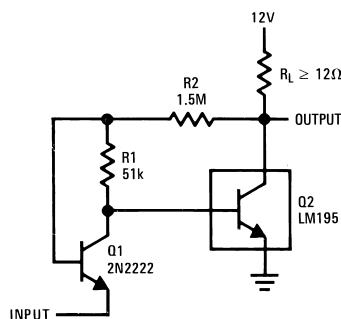
Turn ON = 350 mV
Turn OFF = 200 mV

Product Folder Links: *LM195QML LM195QML-SP*

Power One-Shot
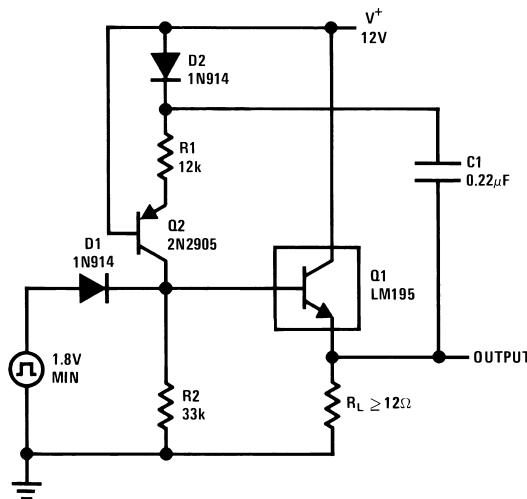

T = R1C
R2 = 3R1
R2 ≤ 82k

Emitter Follower
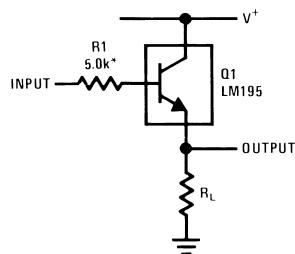
*Need for Stability

High Input Impedance AC Emitter Follower
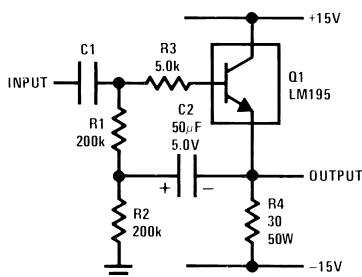
Fast Follower
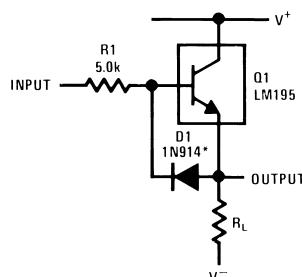
*Prevents storage with fast fall time square wave drive

Submit Documentation Feedback   11

Power Op Amp
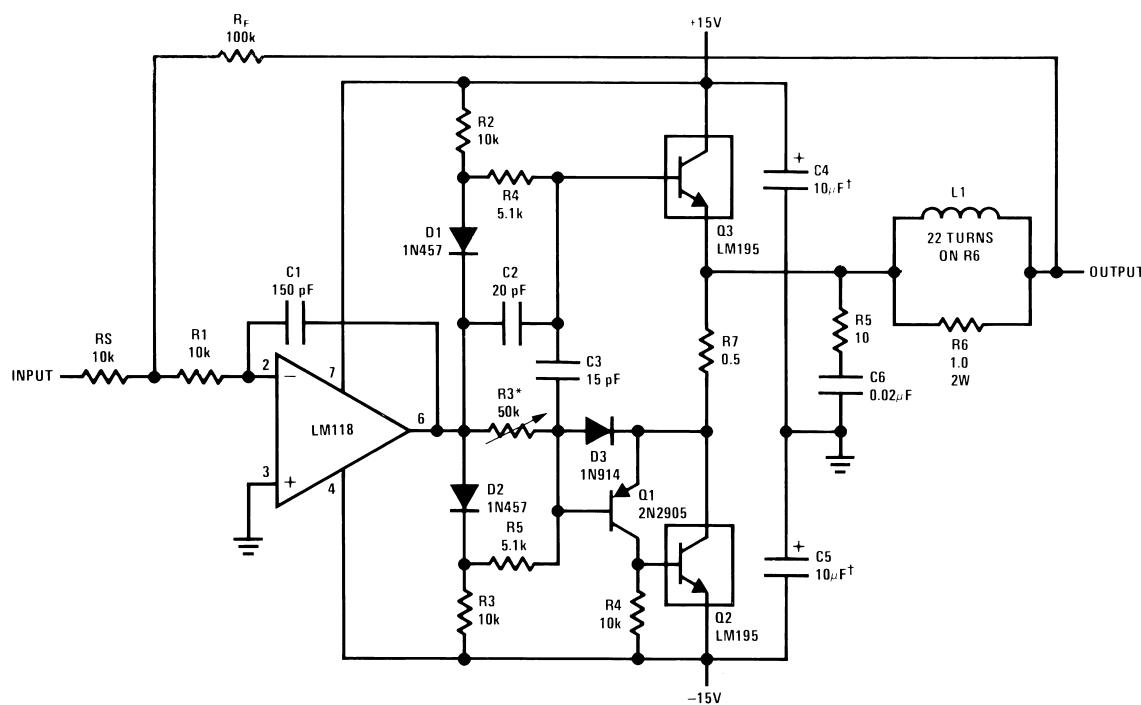
*Adjust for 50 mA quiescent current
†Solid Tantalum

6.0 Amp Variable Output Switching Regulator
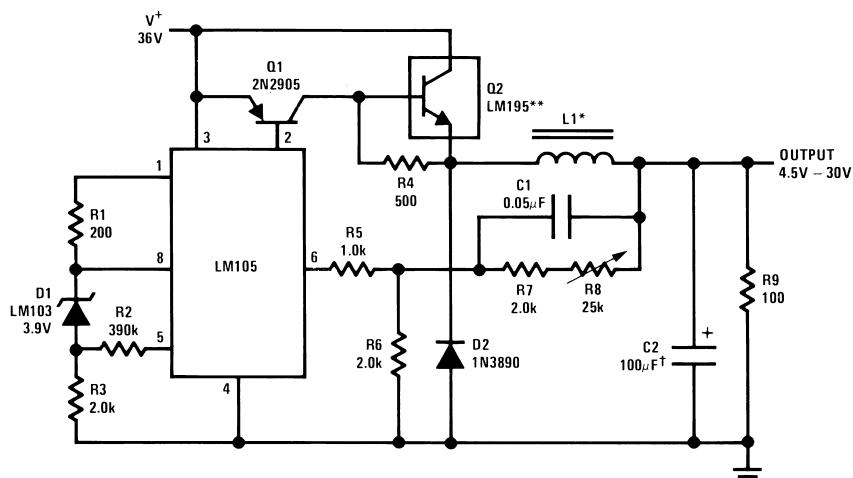
*Sixty turns wound on Arnold Type A-083081-2 core.
**Four devices in parallel
†Solid tantalum

REVISION HISTORY SECTION

Released	Revision	Section	Changes
11/30/2010	A	New Release, Corporate format	1 MDS data sheets converted into one Corp. data sheet format. MNLM195-H Rev 0BL will be archived.
03/20/2013	A	All	Changed layout of National Data Sheet to TI format

Product Folder Links: *LM195QML LM195QML-SP*

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-8777801XA	Active	Production	TO (NDT) | 3	20 | JEDEC TRAY (5+1)	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM195H/883 5962-8777801XA Q A CO 5962-8777801XA Q > T
LM195H/883	Active	Production	TO (NDT) | 3	20 | JEDEC TRAY (5+1)	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM195H/883 5962-8777801XA Q A CO 5962-8777801XA Q > T

(1) Status: For more details on status, see our product life cycle.

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TRAY

L - Outer tray length without tabs

KO - Outer tray height

W - Outer tray width

P1 - Tray unit pocket pitch

CW - Measurement for tray edge (Y direction) to corner pocket center
CL - Measurement for tray edge (X direction) to corner pocket center
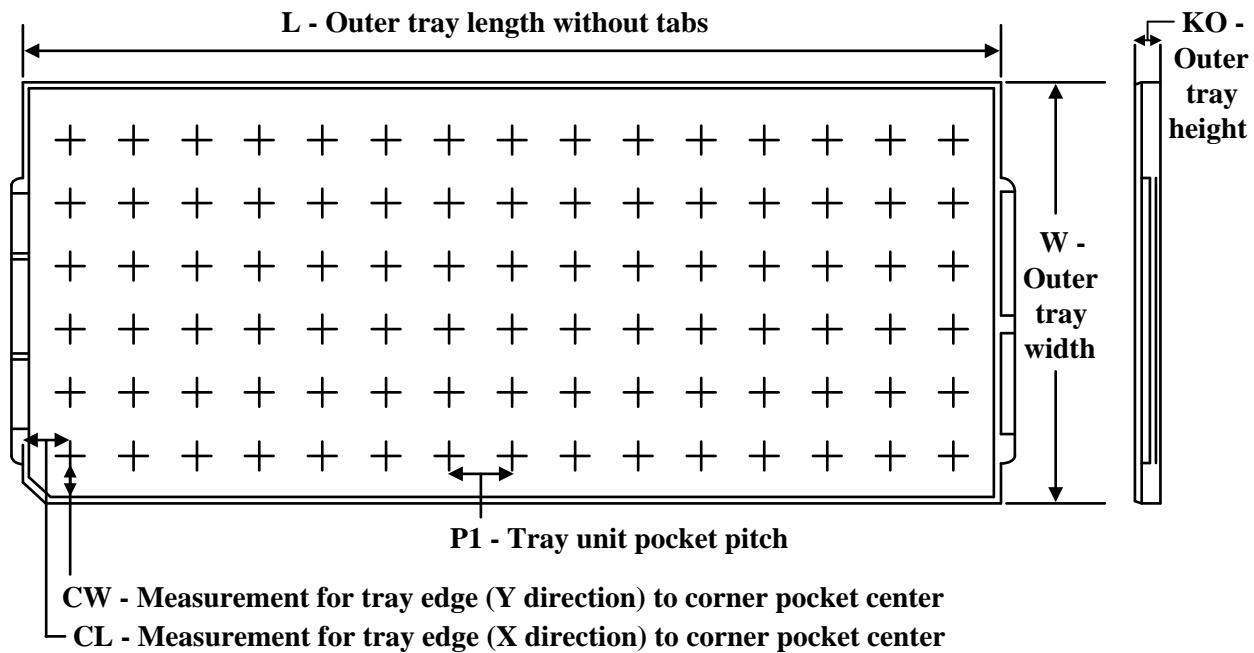
Chamfer on Tray corner indicates Pin 1 orientation of packed units.

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	K0 (µm)	P1 (mm)	CL (mm)	CW (mm)
5962-8777801XA	NDT	TO-CAN	3	20	2 X 10	150	126.49	61.98	8890	11.18	12.95	18.54
LM195H/883	NDT	TO-CAN	3	20	2 X 10	150	126.49	61.98	8890	11.18	12.95	18.54

NDT0003A

Ø.360±.010
[9.14±0.25]

Ø.200
[5.08]

3

2

1

Ø.0175±.0015
[0.445±0.038]
TYP

.035$^{+.005}_{-.006}$
[0.89$^{+0.12}_{-0.15}$]

45°

.031±.003
[0.79±0.07]

SEATING PLANE

.500 MIN
[12.7]

.175±.010
[4.45±0.25]

Ø.325±.010
[8.26±0.25]

.050 MAX
[1.27]

.025 MAX
[0.63]
UNCONTROLLED
LEAD DIA
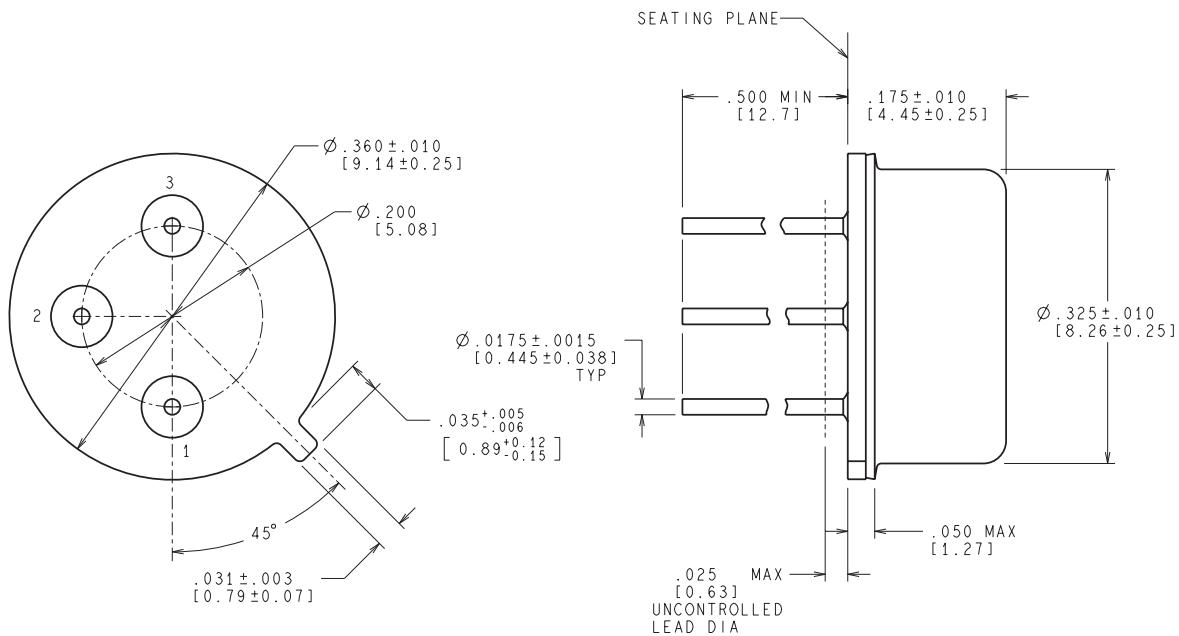
CONTROLLING DIMENSION IS INCH
VALUES IN [ ] ARE MILLIMETERS

MIL-PRF-38535
CONFIGURATION CONTROL

H03A (Rev D)

TEXAS
INSTRUMENTS
www.ti.com

IMPORTANT NOTICE AND DISCLAIMER